DESCRIPTION

The AL1G14 Single Schmitt-trigger inverter is designed for 1.65V to 5.5V Vcc operation.

The AL1G14 contains one inverter and performs the Boolean function $Y=\overline{A}$.

The AL1G14 functions as an independent inverter with Schmitt- trigger inputs, so the device has different input threshold levels for positive-going (V_{T+}) and negative going (V_{T-}) signals to provide hysteresis(ΔV_T) which makes the device tolerant to slow or noisy input signals.

This AL1G14 is fully specified for partial-power-down applications using loff. The loff circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

The AL1G14 is available in SOT-25 and SC70-5 packages and operates over an ambient temperature range of -40°C to +125°C.

FEATURES

- Operating Voltage Range:1.65V to 5.5V
- Inputs Accept voltage to 5.5V
- Low Power Consumption:1µA (Max)
- Operating Temperature Range: -40°C to +125°C
- High Output Drive: ±24mA at Vcc=3.0V
- I_{off} Supports Partial-Power-Down Mode Operation

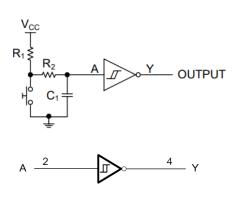
APPLICATION

- AC Receiver
- Audio Dock: Portable
- Blu0ray Player and Home Theater
- Embedded PC
- Portable Media Player/Recorder (Portable Audio)
- Personal Digital Assistant (PDA)
- Power: Telecom/Server AC/DC Supply: Single Controller: Analog and Digital
- Solid State Drive (SSD): Client and Enterprise
- TV: LCD/Digital and High-Definition (HDTB)
- Tablet: Enterprise
- Video Analytics: Server
- Wireless Headset, Keyboard, and Mouse
- Digital Video Cameras (DVC)
- Mobile Phones
- Personal Navigation Device (GPS)

ORDERING INFORMATION

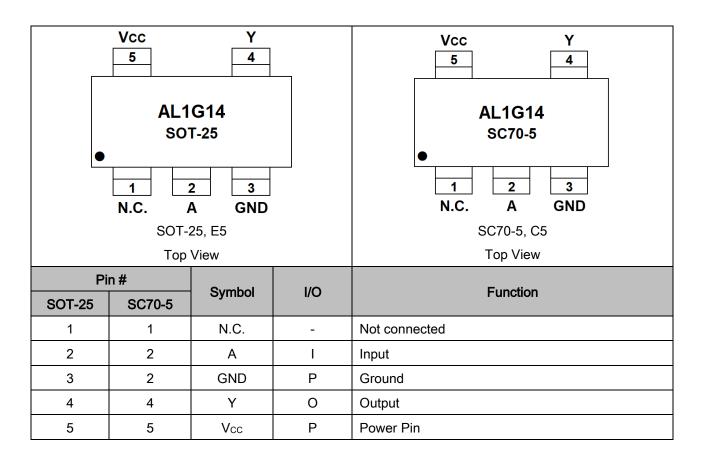
Package Type	Part Number			
SOT-25	E5	AL1G14E5R		
SPQ: 3,000pcs/Reel	EO	AL1G14E5VR		
SC70-5	C5	AL1G14C5R		
SPQ: 3,000pcs/Reel	Co	AL1G14C5VR		
Note	V: Halogen free Package			
Note	R: Tape & Reel			
AiT provides all RoHS products				

FUNCTIONAL BLOCK DIAGRAM



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PIN DESCIPTION



FUNCTION TABLE

Input	Output
Α	Y
Н	L
L	Н

Y=Ā

H=High Voltage Level

L=Low Voltage Level

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ABSOLUTE MAXIMUM RATINGS

T_A = +25°C, unless otherwise noted. (1)

$I_A = +25$ C, unless otherwise noted.	(1)			
V _{CC} , Supply Voltage Range	-0.5V ~ +6.5V			
V _I , Input Voltage Range (1)	-0.5V ~ +6.5V			
Vo, Voltage range applied to any or power-off state (1)	-0.5V ~ +6.5V			
Vo, Voltage range applied to any or	utput in the high or low state (1)(2)	-0.5V ~ V _{CC} +0.5V		
I _{IK} , Input Clamp Current	V _I <0	-50mA		
Іок, Output Clamp Current	Vo<0	-50mA		
Io, Continuous Output Current		±50mA		
Continuous Current Through Vcc o	r GND	±100mA		
T _J , Junction Temperature		150°C		
T _{STG} , Storage Temperature		-65°C ~ +150°C		
ESD Ratings				
V Floatrostatic Dischause	Human-Body Model (HBM)	±8000V		
V _(ESD) , Electrostatic Discharge	Machine Model (MM)	±500V		
Thermal Information				
R _{0JA} , Junction-to-Ambient SOT-25		273.8°C/W		
Thermal Resistance	SC70-5	214.7°C/W		
R _{θJC (top)} , Junction-to-Case(top)	SOT-25	126.8°C/W		
Thermal Resistance	SC70-5	127.1°C/W		

Stresses above may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated in the Electrical Characteristics are not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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⁽¹⁾ The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

⁽²⁾ The value of VCC is provided in the Recommended Operating Conditions table.

RECOMMENDED OPERATING CONDITIONS

T_A = +25°C, unless otherwise noted. (1)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Cumple Maltage	V _{CC}	Operating	1.65	-	5.5		
Supply Voltage		Data retention only	1.5	-	-	V	
Input Voltage	Vı		0	-	5.5	V	
Output Voltage	Vo		0	-	Vcc	V	
Operating Temperature	T _A		-40	-	+125	°C	

AC ELECTRICAL CHARACTERISTICS

TA = +25°C, unless otherwise noted. (1)

Parameter	Symbol	Conditions			Тур.	Max.	Unit
Propagation Delay		V _{CC} =1.8V±0.15V	C_L =30pF, R_L =500 Ω	-	7.5	-	ns
		V _{CC} =2.5V±0.2V	C _L =30pF, R _L =500Ω	-	3.6	-	
	t _{pd}	V _{CC} =3.3V±0.3V	C _L =50pF, R _L =500Ω	-	3.1	-	
		V _{CC} =5V±0.5V	C _L =50pF, R _L =500Ω	-	2.7	-	
Input Capacitance	Ci	V _{CC} =3.3V	V _I =V _{CC} or GND	-	4	-	рF
Power Dissipation Capacitance		V _{CC} =1.8V	f=10MHz	-	20	-	
		V _{CC} =2.5V		-	21	-	
	$C_{\sf pd}$	V _{CC} =3.3V		-	22	-	pF
		V _{CC} =5V		-	25	-	

⁽¹⁾ All unused inputs of the device must be held at VCC or GND to ensure proper device operation.

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DC ELECTRICAL CHARACTERISTICS

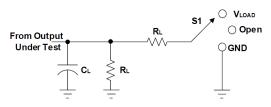
 T_A = +25°C, unless otherwise noted. (1)

Parameter		Conditions		Min.	Тур.	Max.	Unit
		V _{CC} =1.65V, T _A =-40		0.75	-	1.05	
		V _{CC} =2.3V, T _A =-40°(1.25	-	1.55	
V _T	Positive Going Input	V _{CC} =3V, T _A =-40°C to +125°C 1.5				2.1	V
	Threshold Voltage	V _{CC} =4.5V, T _A =-40°	C to +125°C	2.3	-	3.0	
		V _{CC} =5.5V, T _A =-40°0	C to +125°C	2.8	-	3.4	
		V _{CC} =1.65V , T _A =-40°C to +125°C		0.3	-	0.6	
	No of a Odio Loo	V _{CC} =2.3V, T _A =-40°C to +125°C		0.35	-	0.65	
V_{T-}	Negative Going Input	V _{CC} =3V, T _A =-40°C	to +125°C	0.45	-	0.75	V
	Threshold Voltage	V _{CC} =4.5V, T _A =-40°	C to +125°C	0.7	-	1.0	
		V _{CC} =5.5V, T _A =-40°0	C to +125°C	0.85	-	1.15	
		V _{CC} =1.65V, T _A =-40	°C to +125°C	0.35	-	0.6	
		V _{CC} =2.3V, T _A =-40°	C to +125°C	0.6	-	1.2	
ΔV_{T}	Hysteresis (V _{T+} - V _{T-})	V _{CC} =3V, T _A =-40°C	to +125°C	1.05	-	1.65	V
		V _{CC} =4.5V, T _A =-40°C to +125°C		1.6	-	2.0	
	V _{CC} =5.5V, T _A =-40°0	C to +125°C	1.95	-	2.25		
		I _{OH} = -100μA, V _{CC} =1.65V to 5.5V		V _{CC} - 0.1	-	-	
		I _{OH} =-4mA, V _{CC} =1.65V		1.2	-	-	V
V _{OH}	0.1	I _{OH} =-8mA, V _{CC} =2.3V		1.9	-	-	
I _A =-40°	C to +125°C	I _{OH} =-16mA, V _{CC} =3V		2.4	-	-	
		I _{OH} =-24mA, V _{CC} =3V		2.3	-	-	
		I _{OH} =-32mA, V _{CC} =4.5V		3.8	-	-	
		I _{OL} =100μA, V _{CC} =1.65V to 5.5V		-	-	0.1	
		I _{OL} =4mA, V _{CC} =1.65V		-	-	0.45	
V_{OL}		I _{OL} =8mA, V _{CC} =2.3V		-	-	0.3	.,
T _A =-40°	C to +125°C	I _{OL} =16mA, V _{CC} =3V		-	-	0.4	V
		I _{OL} =24mA, V _{CC} =3V		-	-	0.55	
		I _{OL} =32mA, V _{CC} =4.5	V	-	-	0.55	
	A input	V _I =5.5V or GND	T _A =-25°C	-	±0.1	±1	μΑ
l _l	Ainput	V _{CC} = 0V to 5.5V	T _A =-40°C to +125°C	-	-	±5	
l _{off}		V⊦or Vo=5.5V	T _A =-25°C		±0.1	±1	
		V _{CC} =0V	T _A =-40°C to +125°C			±10	μΑ
Icc		V _I =5.5V or GND I _O =0,	T _A =-25°C	-	0.1	1	
		V _{CC} =1.65V to 5.5V	T _A =-40°C to +125°C	-	_	10	μA
Δlcc T _A =-40°C to +125°C		One input at V _{CC} - 0.6V, Other inputs at V _{CC} or GND V _{CC} =3V to 5.5V		-	-	500	μΑ

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DETAILED INFORMATION

Parameter Measurement Information



TEST	S1
t _{PZL} (see E and F)	V_{LOAD}
t _{PLZ} (see E and G)	V_{LOAD}
t _{PHZ} /t _{PZH}	V_{LOAD}

V	Inputs		\/	W	V C-		V	
Vcc	Vı	t _r /t _f	V _M	VLOAD	C∟	R∟	VΔ	
1.8V±0.15V	Vcc	≤2ns	Vcc/2	2 x Vcc	30pF	1kΩ	0.15V	
2.5V±0.2V	Vcc	≤2ns	V _{CC} /2	2 x V _{CC}	30pF	500Ω	0.15V	
3.3V±0.3V	3V	≤2.5ns	1.5V	6V	50pF	500Ω	0.3V	
5V±0.5V	Vcc	≤2.5ns	Vcc/2	2 x Vcc	50pF	500Ω	0.3V	

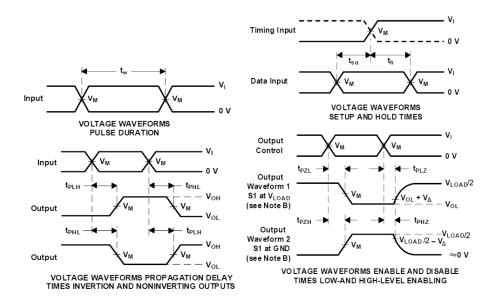


Figure 1. Load Circuit and Voltage Waveforms

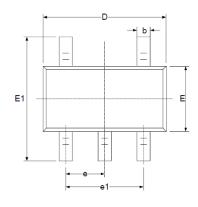
- (A) C_L includes probe and jig capacitance.
- (B) Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- (C) All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_0 = 50 Ω .
- (D) The outputs are measured one at a time, with one transition per measurement.
- (E) Since this device has open-drain outputs, t_{PLZ} and t_{PZL} are the same as t_{pd} .
- (F) t_{PZL} is measured at V_M.
- (G) t_{PLZ} is measured at $V_{OL} + V_{\Delta}$.
- (H) All parameters and waveforms are not applicable to all devices.

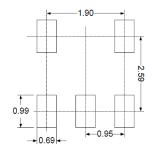
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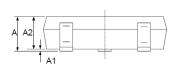
PACKAGE INFORMATION

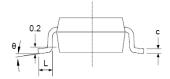
Dimension in SOT-25 (Unit: mm)





RECOMMENDED LAND PATTERN

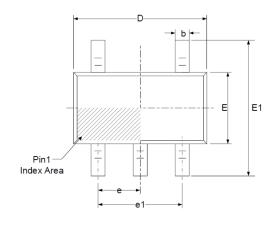


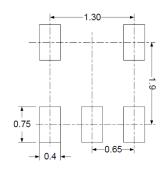


Cumbal	Millim	neters		
Symbol	Min	Max		
Α	1.050	1.250		
A1	0.000	0.100		
A2	1.050	1.150		
b	0.300	0.500		
С	0.100	0.200		
D	2.820	3.020		
E	1.500	1.700		
E1	2.650	2.950		
е	0.950 BSC			
e1	1.800	2.000		
L	0.300	0.600		
θ	0°	8°		

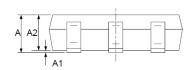
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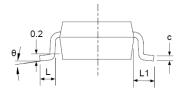
Dimension in SC70-5 (Unit: mm)





RECOMMENDED LAND PATTERN





Cymbol	Millim	neters		
Symbol	Min	Max		
Α	0.900	1.100		
A1	0.000	0.100		
A2	0.900	1.000		
b	0.150	0.350		
С	0.080	0.150		
D	2.000	2.200		
E	1.150	1.350		
E1	2.150	2.450		
е	0.650	BSC		
e1	1.300 BSC			
L	0.260	0.460		
L1	0.525			
θ	0° 8°			

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